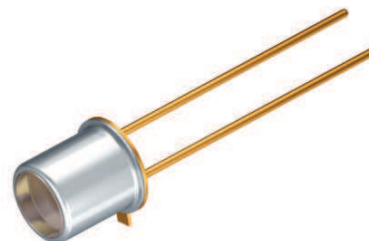


# Silicon PIN Photodiode

## Version 1.3

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### BPX 65



#### Features:

- Wavelength range ( $S_{10\%}$ ) 350 nm to 1100 nm
- Short switching time (typ. 12 ns)
- Hermetically sealed metal can package (TO-18), suitable up to 125 °C

#### Applications

- Industrial electronics
- For control and drive circuits
- High speed photo detector

#### Ordering Information

| Type:  | Photocurrent<br>$I_P$ [ $\mu$ A]<br>$E_V = 1000$ lx, Std. Light A, $V_R = 5$ V | Ordering Code |
|--------|--|---------------|
| BPX 65 | 10 ( $\geq 5.5$ )  | Q62702P0027   |

**Maximum Ratings** ( $T_A = 25\text{ °C}$ )

| Parameter   | Symbol            | Values      | Unit |
|---|-------------------|-------------|------|
| Operating and storage temperature range                           | $T_{op}; T_{stg}$ | -40 ... 125 | °C   |
| Reverse voltage   | $V_R$             | 20          | V    |
| Reverse voltage<br>( $t < 2\text{ min}$ )                         | $V_R$             | 50          | V    |
| Total Power dissipation   | $P_{tot}$         | 250         | mW   |
| ESD withstand voltage<br>(acc. to ANSI/ ESDA/ JEDEC JS-001 - HBM) | $V_{ESD}$         | 2000        | V    |

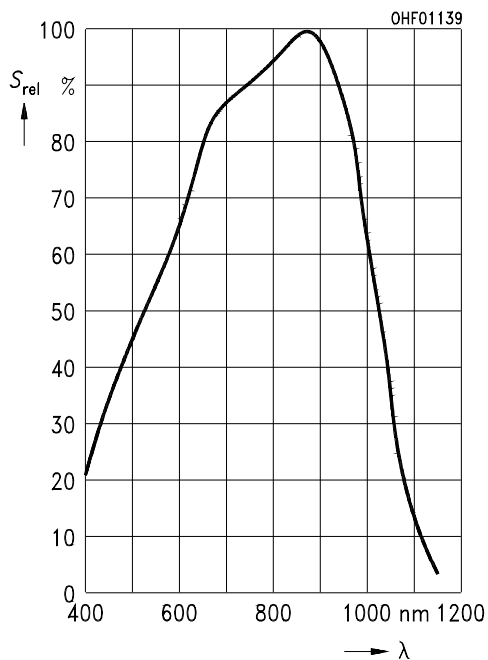
**Characteristics** ( $T_A = 25\text{ °C}$ )

| Parameter   | Symbol                         | Values                | Unit               |
|---|--------------------------------|-----------------------|--------------------|
| Spectral sensitivity<br>( $V_R = 5\text{ V}$ )  | (typ) S                        | 10 ( $\geq 5.5$ )     | nA/lx              |
| Photocurrent<br>( $E_v = 1000\text{ lx}$ , Std. Light A, $V_R = 5\text{ V}$ )                 | (typ (min)) $I_P$              | 10 ( $\geq 5.5$ )     | $\mu\text{A}$      |
| Wavelength of max. sensitivity  | (typ) $\lambda_{S\text{ max}}$ | 850                   | nm                 |
| Spectral range of sensitivity   | (typ) $\lambda_{10\%}$         | (typ) 350<br>... 1100 | nm                 |
| Radiant sensitive area  | (typ) A                        | 1.00                  | $\text{mm}^2$      |
| Dimensions of radiant sensitive area  | (typ) L x W                    | 1 x 1                 | mm x mm            |
| Half angle  | (typ) $\varphi$                | $\pm 40$              | °                  |
| Dark current<br>( $V_R = 20\text{ V}$ )   | (typ (max)) $I_R$              | 1 ( $\leq 5$ )        | nA                 |
| Spectral sensitivity of the chip<br>( $\lambda = 850\text{ nm}$ )                             | (typ) $S_{\lambda\text{ typ}}$ | 0.55                  | A / W              |
| Quantum yield of the chip   | (typ) $\eta$                   | 0.80                  | Electrons / Photon |
| Open-circuit voltage<br>( $E_v = 1000\text{ lx}$ , Std. Light A)                              | (typ (min)) $V_O$              | 320 ( $\geq 270$ )    | mV                 |
| Short-circuit current<br>( $E_v = 1000\text{ lx}$ , Std. Light A)                             | (typ) $I_{SC}$                 | 10                    | $\mu\text{A}$      |
| Rise and fall time<br>( $V_R = 5\text{ V}$ , $R_L = 50\ \Omega$ , $\lambda = 850\text{ nm}$ ) | (typ) $t_r, t_f$               | 0.012                 | $\mu\text{s}$      |
| Forward voltage<br>( $I_F = 100\text{ mA}$ , $E = 0$ )  | (typ) $V_F$                    | 1.3                   | V                  |
| Capacitance<br>( $V_R = 0\text{ V}$ , $f = 1\text{ MHz}$ , $E = 0$ )                          | (typ) $C_0$                    | 11                    | pF                 |

| Parameter   |       | Symbol | Values | Unit                          |
|---|-------|--------|--------|-------------------------------|
| Temperature coefficient of $V_O$                              | (typ) | $TC_V$ | -2.6   | mV / K                        |
| Temperature coefficient of $I_{SC}$<br>(Std. Light A)         | (typ) | $TC_I$ | 0.18   | % / K                         |
| Noise equivalent power<br>( $V_R = 20$ V, $\lambda = 850$ nm) | (typ) | NEP    | 0.033  | pW /<br>Hz <sup>1/2</sup>     |
| Detection limit   | (typ) | $D^*$  | 3.1e12 | cm x<br>Hz <sup>1/2</sup> / W |

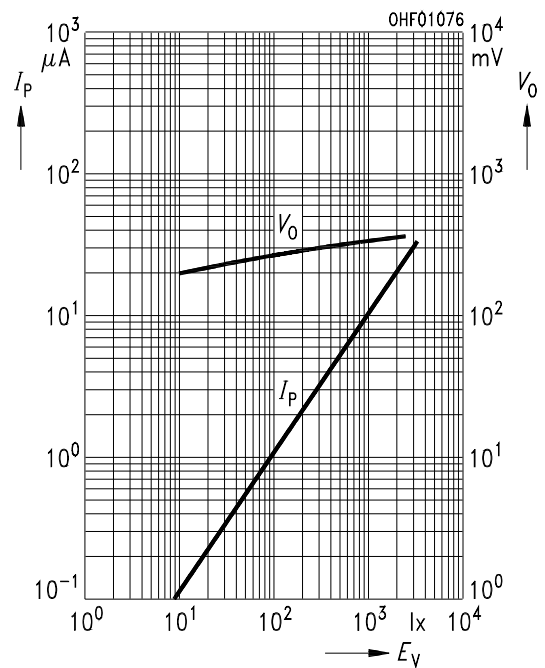
### Relative Spectral Sensitivity <sup>1) page 7</sup>

$$S_{rel} = f(\lambda)$$



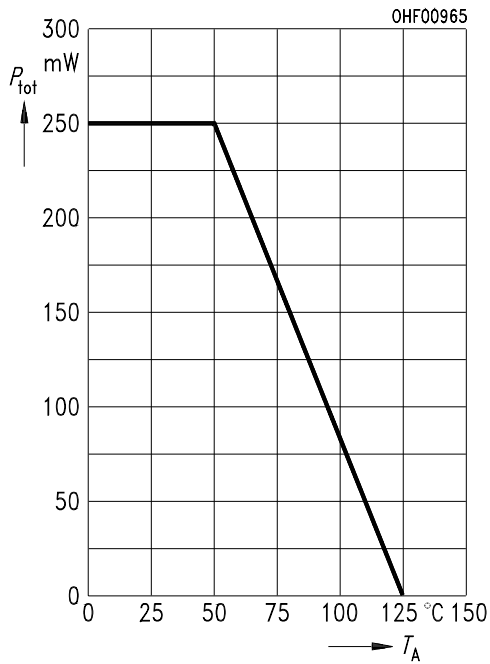
### Photocurrent / Open-Circuit Voltage <sup>1) page 7</sup>

$$I_P (V_R = 5 \text{ V}) / V_O = f(E_V)$$



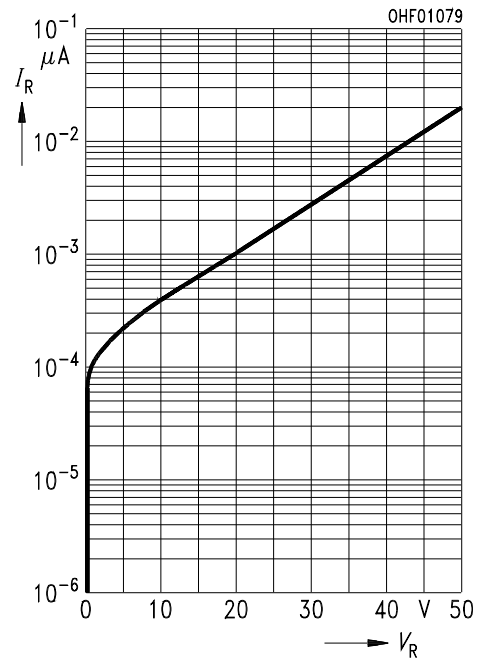
**Power Consumption**

$P_{tot} = f(T_A)$



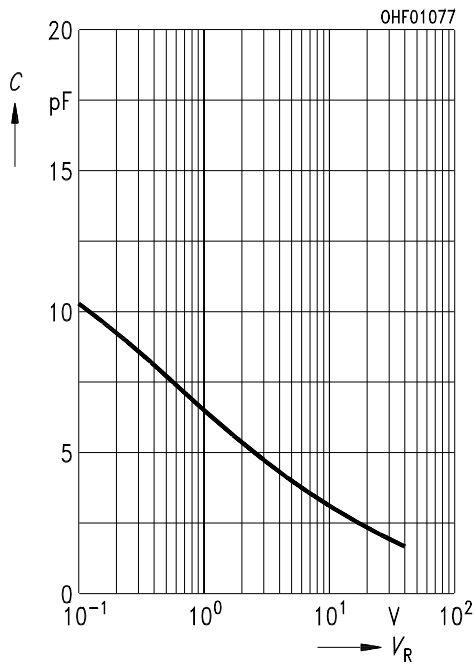
**Dark Current** <sup>1) page 7</sup>

$I_R = f(V_R), E = 0$



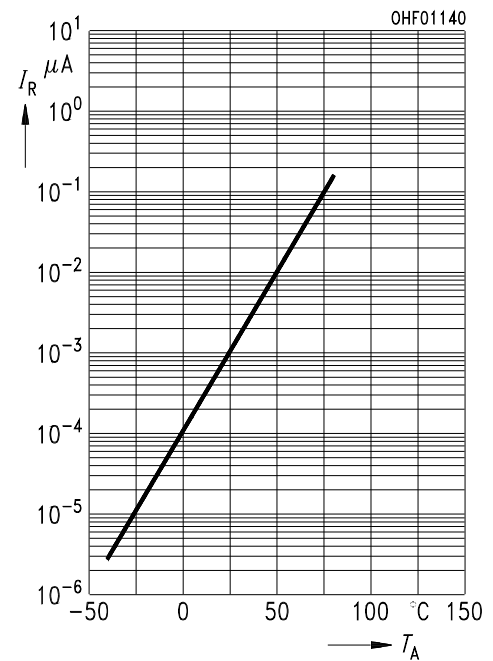
**Capacitance** <sup>1) page 7</sup>

$C = f(V_R), f = 1 \text{ MHz}, E = 0$



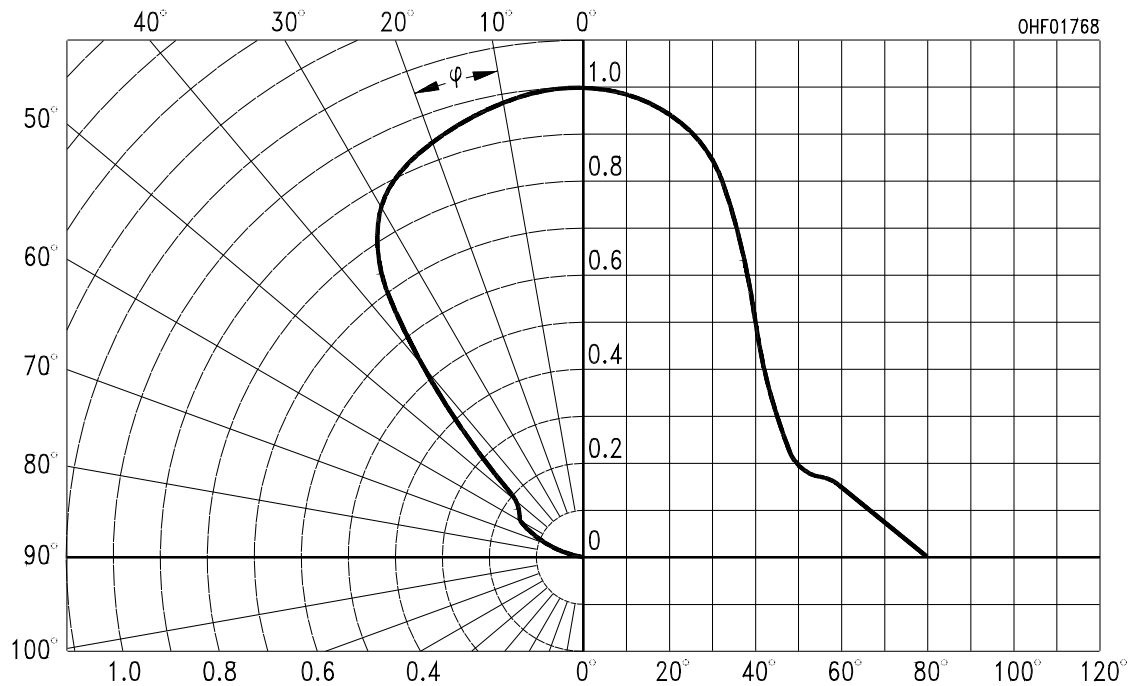
**Dark Current** <sup>1) page 7</sup>

$I_R = f(T_A), V_R = 20 \text{ V}, E = 0$

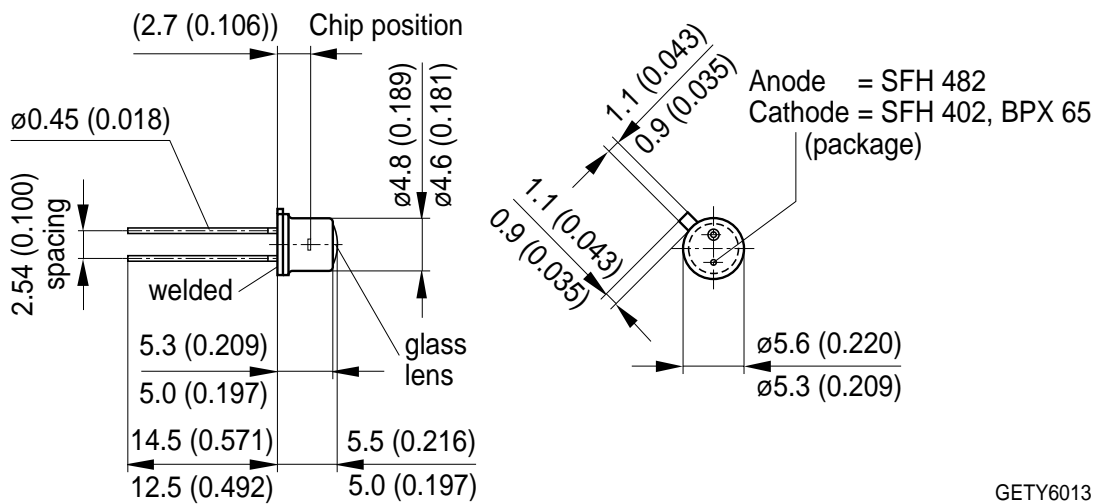


**Directional Characteristics** <sup>1) page 7</sup>

$S_{rel} = f(\phi)$



**Package Outline**



*Dimensions in mm (inch).*

**Package**

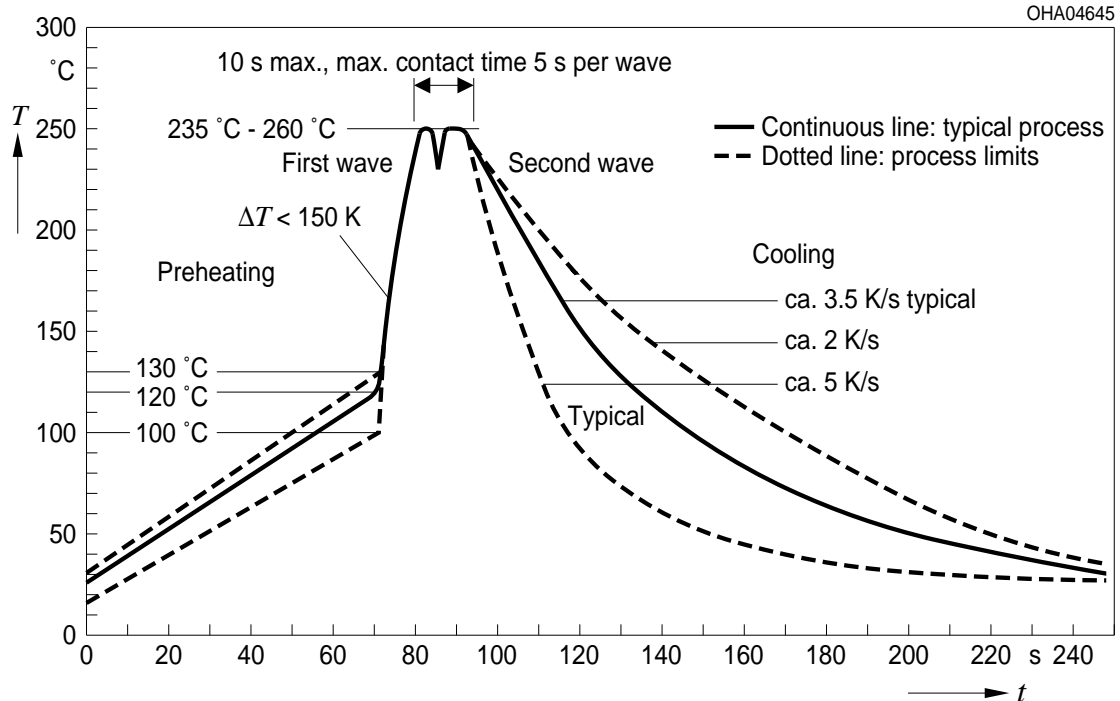
Metal Can (TO-18), hermetically sealed

**Approximate Weight:**

0.3 g

**TTW Soldering**

IEC-61760-1 TTW

**Disclaimer**

Language english will prevail in case of any discrepancies or deviations between the two language wordings.

**Attention please!**

The information describes the type of component and shall not be considered as assured characteristics.

Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version in the Internet.

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Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

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\*) A critical component is a component used in a life-support device or system whose failure can reasonably be expected to cause the failure of that life-support device or system, or to affect its safety or the effectiveness of that device or system.

\*\*) Life support devices or systems are intended (a) to be implanted in the human body, or (b) to support and/or maintain and sustain human life. If they fail, it is reasonable to assume that the health and the life of the user may be endangered.

**Glossary**

- <sup>1)</sup> **Typical Values:** Due to the special conditions of the manufacturing processes of LED, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.

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